TOSHIBA Field Effect Transistor Silicon N Channel MOS Type(U-MOSIX-H)

SSM6K513NU

Power Management Switch Applications

- 4.5V drive
- Low ON-resistance: RDS(ON) = 8.0 m Ω (typ.) (@VGS = 4.5V) RDS(ON) = 6.5 m Ω (typ.) (@VGS = 10 V)

Absolute Maximum Ratings (Ta = 25°C)

Charac	teristics	Symbol	Rating	Unit	
Drain-Source voltage		V _{DSS}	30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	ID	15	A	
	Pulse	IDP (Note 2)	50		
Power dissipation		P _D (Note 3)	1.25	w	
		t≦10s	2.5	VV	
Single-pulse avalanche energy		Eas (Note 4)	17.9	mJ	
Avalanche current		lar	15	Α	
Channel temperature		T _{ch}	150	°C	
Storage temperatu	re	T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $PW \le 10us$, $Duty \le 1\%$

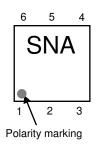
Note 3: Mounted on a FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: } 645 \text{ mm}^2)$

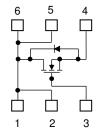
Note 4: VDD = 24 V, Tch = 25° C (Initial state), L = 50μ H, RG = 25Ω ,

Weight: 8.5 mg (typ.)

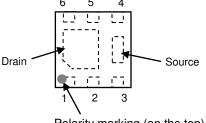
Marking(Top View)



Equivalent Circuit(Top View)



Pin Condition(Top View)



Polarity marking (on the top)
*Electrodes : on the bottom

Electrical Characteristics (Ta = 25°C)

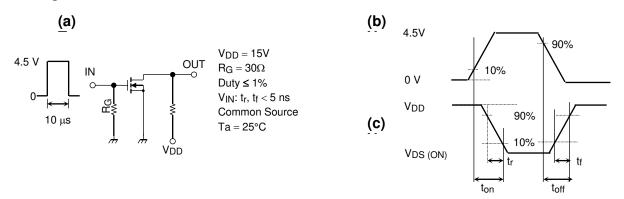
Chara	cteristic	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$		30	_	_	V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	(Note 5)	27	_	_	٧
Drain cut-off current		I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V		_	_	1	μА
Gate leakage current		IGSS	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±100	nA
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 0.1 mA		1.1	_	2.1	٧
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 2.0 A	(Note 6)	_	6.8	_	S
Drain-source ON-resistance		R _{DS} (ON)	I _D = 4 A, V _{GS} = 10 V	(Note 6)	_	6.5	8.9	mΩ
			I _D = 4 A, V _{GS} = 4.5 V	(Note 6)	_	8.0	12	
Input capacitance		C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		_	1130		pF
Output capacitance		Coss			_	350		
Reverse transfer capacitance		C _{rss}			_	52		
Total Gate Charge		Qg	V _{DD} = 15 V, I _D = 15 A V _{GS} = 4.5 V		_	7.5	_	nC
Gate-Source Charge1		Q _{gs1}			_	3.0	_	
Gate-Drain Charge		Qgd			_	2.2	_	
Switching time	Turn-on time	t _{on}	V _{DD} = 15 V, I _D = 1.0 A,		_	28		
	Turn-off time	toff	$V_{GS} = 0$ to 4.5 V, $R_{G} = 30 \Omega$		_	33	_	ns
Drain-Source forward voltage		V _{DSF}	I _D = -4.0 A, V _G S = 0 V	(Note 3)	_	-0.76	-1.2	٧

Note 5: If a reverse bias is applied between gate and source, this device enters V(BR)DSX mode.

Note that the drain-source breakdown voltage is lowered in this mode

Note 6: Pulse test

Switching Time Test Circuit



Precaution

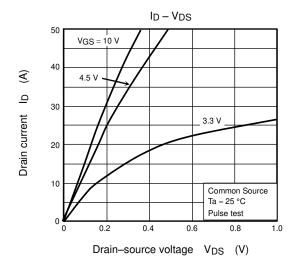
Let Vth be the voltage applied between gate and source that causes the drain current (ID) to be low (0.1 mA for the SSM6K513NU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than Vth, and $V_{GS(off)}$ must be lower than Vth. This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

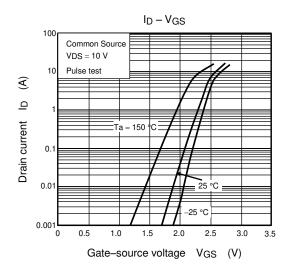
Take this into consideration when using the device.

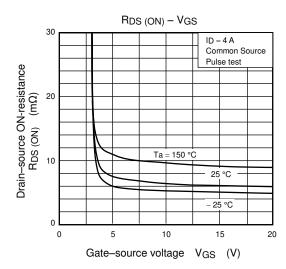
Handling Precaution

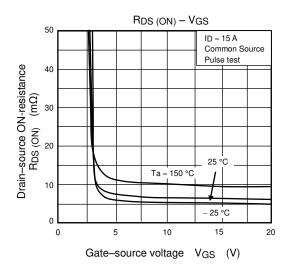
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

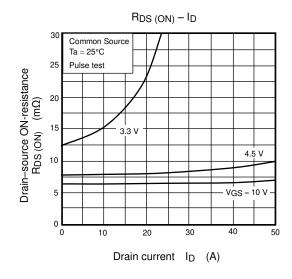
Thermal resistance Rth (ch-a) and power dissipation PD vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

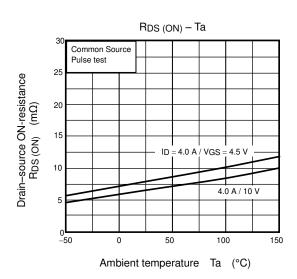


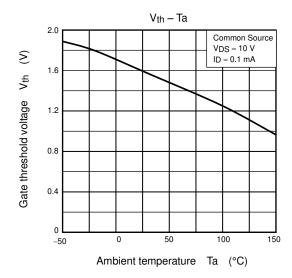


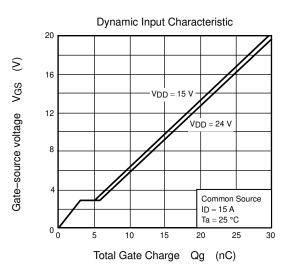


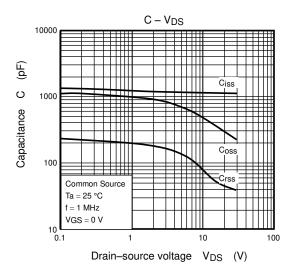


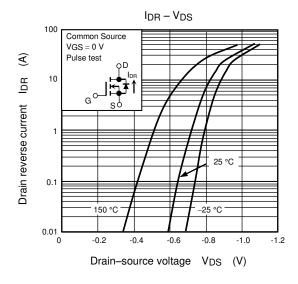


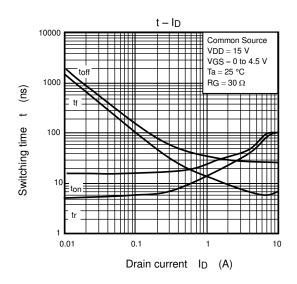


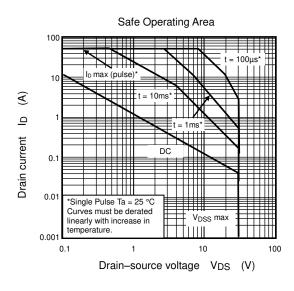




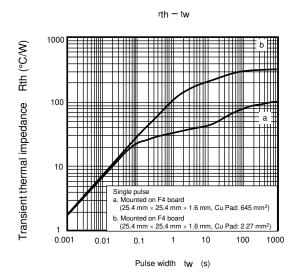


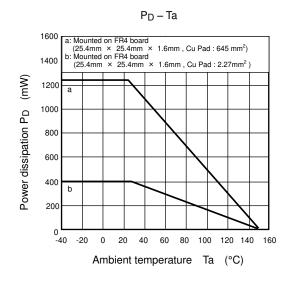






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